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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Complete	if Known
Application Number	10/593,107
Filing Date	October 25, 2007
First Named Inventor:	Shu Yuan
Art Unit	2892
Examiner Name	Pham, Hoai V.
Attorney Docket Number	7989P003

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			U.S. PAT	ENT DOCUMENTS		
Examiner Initials*	Cite No.		Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant
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* only Abstract in English

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Application Number	10/593,107
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First Named Inventor:	Shu Yuan
Art Unit	2892
Examiner Name	Pham, Hoai V.
Attorney Docket Number	7989P003

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* only Abstract in English

Examiner /Hoai Pham/	Date Considered	02/27/2010
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Complete	if Known
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Examiner	Cite	Foreign Patent Document	Publication	Name of Patentee or	Pages, Columns,	T 6
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Signature	/Hoai Pham/	Jule Constacted	02/27/2010

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INFORMATION DISCLOSURE					Application Number	10/593,107		
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(use as many sheets as necessary)					Art Unit	2892		
					Examiner Name	Pham, Hoai V.		
Sheet	4		of	5	Attorney Docket Number	7989P003		
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Examiner Initials*	Cite No ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published						
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Examiner	/Hoai Pham/	Date	02/27/2010
Signature	/noai rnani/	Considered	06/20166919

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Sheet	5	5 of 5				Attorney Docket Number	7989P003			
Officer	<u>~</u>		<u> </u>		- NIT 1 IT		1 7 0001 000			
Examiner Initials*	Cite No ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published PCT International Search Report for PCT Application No. PCT/SG2005/000062 containing Communication relating to the Results of the Partial International Search Report, 2 pgs., (May 12, 2005).							T ²	
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